

勝特力電材超市-龍山店 886-3-5773766 勝特力電材超市-光復店 886-3-5729570 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 http://www.100v.com.tw

Features

- $BV_{CEO} > 60V$
- I_C = 2A High Continuous Collector Current
- I_{CM} = 6A Peak Pulse Current
- T_J up to +200°C for High Temperature Operation
- Low Saturation Voltage < 300mV @ 1A
- P_D = 1W Power dissipation
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: E-Line (TO-92 Compatible)
- Case Material: molded plastic, "Green" Molding Compound

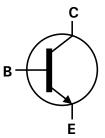
60V NPN MEDIUM POWER TRANSISTOR IN E-LINE

- UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.159 grams (approximate)

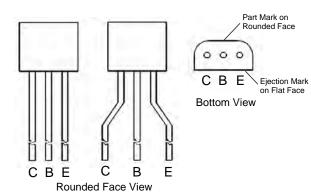
E-Line (TO-92 Compatible)







Device Symbol



Pin-Out Configuration

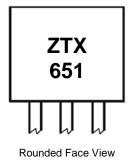
Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Case	Leads	Quantity
ZTX651	AEC-Q101	ZTX651	E-Line	Straight	4,000 loose in a Box
ZTX651Q	Automotive	ZTX651	E-Line	Straight	4,000 loose in a Box
ZTX651STZ	AEC-Q101	ZTX651	E-Line	Joggled	2,000 taped per Ammo Box
ZTX651QSTZ	Automotive	ZTX651	E-Line	Joggled	2,000 taped per Ammo Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZTX651 = Product type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	lc	2	Α
Peak Pulse Current	Ісм	6	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	1.5	W
Power Dissipation (Note 7)	P _D	1	W
Thermal Resistance Junction to Ambient (Note 6)	R _{0JA}	116	°C/W
Thermal Resistance Junction to Ambient (Note 7)	Roja	175	°C/W
Thermal Resistance Junction to Lead (Note 8)	Rojl	70	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +200	°C

ESD Ratings (Note 9)

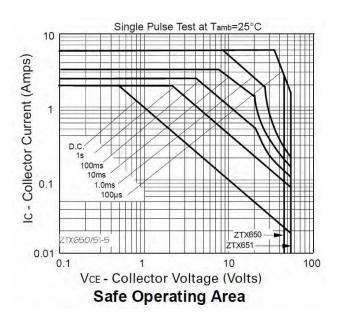
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

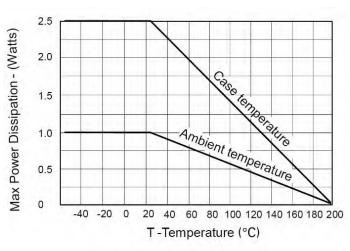
Notes:

- 6. For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note (5), except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
- 8. Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

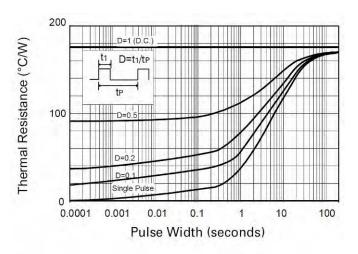


Thermal Characteristics and Derating Information





Derating curve



Maximum transient thermal impedance





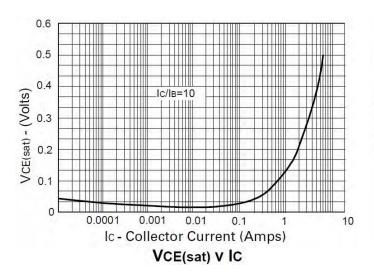
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

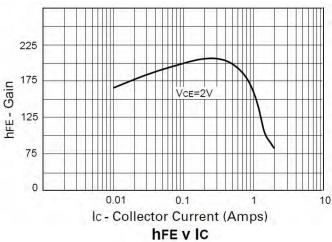
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	80	_		V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	60	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	_		V	$I_E = 100\mu A$
Collector Cut-off Current	Ісво	_	_	0.1 10	μA μA	$V_{CB} = 60V$ $V_{CB} = 60V, T_{amb} = 100^{\circ}C$
Emitter Cut-off Current	I _{EBO}	_	_	0.1	μΑ	$V_{EB} = 6V$
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	_	120 230	300 500	mV	$I_C = 1A$, $I_B = 100mA$ $I_C = 2A$, $I_B = 200mA$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	_	0.9	1.25	V	$I_C = 1A$, $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	0.8	1	V	I _C = 1A, V _{CE} = 2V
DC Current Gain (Note 10)	hFE	70 100 80 40	200 200 170 80	300 — —	_	$I_C = 50$ mA, $V_{CE} = 2V$ $I_C = 500$ mA, $V_{CE} = 2V$ $I_C = 1$ A, $V_{CE} = 2V$ $I_C = 2$ A, $V_{CE} = 2V$
Current Gain-Bandwidth Product (Note 10)	f⊤	140	175	1	MHz	$V_{CE} = 5V, I_{C} = 100mA$ f = 100MHz
Output Capacitance (Note 10)	C _{obo}	_		30	pF	V _{CB} = 10V. f = 1MHz
Turn-On Times	t _{on}	_	45	_	ns	$I_C = 500 \text{mA}, I_{B1} = I_{B2} = 50 \text{mA},$
Turn-Off Times	t _{off}	_	800		ns	V _{CC} = 10V

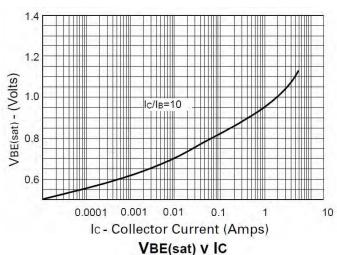
Notes: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

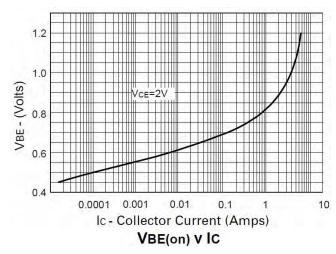


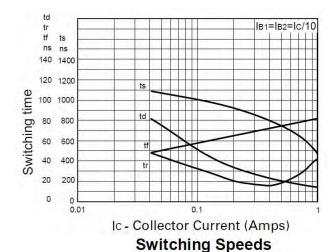
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)









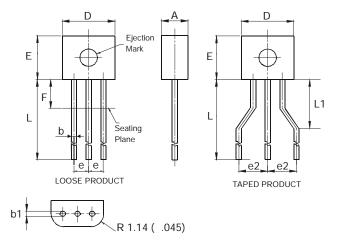






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



E-Line					
Dim	Min	Max	Тур		
Α	2.16	2.41	_		
b	0.41	0.495	_		
b1	0.41	0.495	_		
D	4.37	4.77	_		
Е	3.61	4.01	-		
е	_	_	1.27		
e2	-	-	2.54		
F	_	2.50	_		
L	13.00	13.97	-		
L1	2.50	3.50	_		
All Dimensions in mm					

勝特力電材超市-龍山店 886-3-5773766 勝特力電材超市-光復店 886-3-5729570 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 http://www.100y.com.tw